

Dual N-Channel Power MOSFET

20V, 5.8A, 25mΩ

Features

- Halogen-free
- Suited for 1.8V drive applications
- Low profile package

APPLICATION

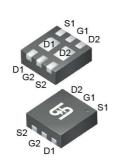
- Battery Pack
- Load Switch

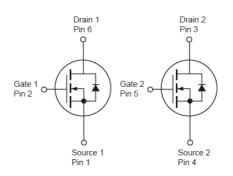
KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
V_{DS}		20	V	
R _{DS(on)} (max)	$V_{GS} = 4.5V$	25		
	$V_{GS} = 2.5V$	35	mΩ	
	$V_{GS} = 1.8V$	55		
Q_g		7.7	nC	











Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V_{GS}	±10	V
Continuous Drain Current (Note 1)	T _C = 25°C		5.8	
Continuous Drain Current	T _C = 100°C	I _D	3.48	А
Pulsed Drain Current (Note 2)		I _{DM}	23.2	Α
Total Power Dissipation @ T _C = 25°C		P _{DTOT}	0.62	W
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Ambient Thermal Resistance	R _{OJA}	200	°C/W	

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air.

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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 3)	,			1	1	
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	0.4	0.6	0.8	V
Gate Body Leakage	$V_{GS} = \pm 10V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	V _{DS} =16V, V _{GS} =0V	I _{DSS}			1	μA
Drain-Source On-State Resistance	$V_{GS} = 4.5V, I_D = 4A$			20	25	mΩ
	$V_{GS} = 2.5V, I_D = 3A$	R _{DS(on)}		27	35	
	$V_{GS} = 1.8V, I_D = 2A$			39	55	
Forward Transconductance	V _{DS} =10V, I _D =3A	g _{fs}		6.5		S
Dynamic (Note 4)						
Total Gate Charge		Q_g		7.7	11	
Gate-Source Charge	$V_{DS} = 10V, I_{D} = 4A,$	Q _{gs}		0.9	1	nC
Gate-Drain Charge	$V_{GS} = 4.5V$	Q_{gd}		2.4	5	
Input Capacitance		C _{iss}		535	775	
Output Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$	C _{oss}		60	85	pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		34	50	
Switching (Note 5)				•	•	1
Turn-On Delay Time		t _{d(on)}		4.1	8	
Turn-On Rise Time	$V_{DD} = 10V, I_{D} = 1A,$	t _r		11.6	22	
Turn-Off Delay Time	$V_{GS} = 4.5V, R_G = 25\Omega$	t _{d(off)}		23.9	45	ns
Turn-Off Fall Time		t _f		7.6	14	
Source-Drain Diode (Note 3)		•	•	•	•	
Continuous Source Current	$V_G=V_D=0V$,	I _S			5.8	А
Pulsed Source Current	Force Current	I _{SM}			23.2	Α
Forward On Voltage	$V_{GS} = 0V, I_{S} = 1A$	V _{SD}			1	V
	•	•	•	•	•	

Notes:

- 1. Current limited by package.
- 2. Pulse width limited by the maximum junction temperature.
- 3. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%.
- 4. For DESIGN AID ONLY, not subject to production testing.
- 5. Switching time is essentially independent of operating temperature.



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ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM250N02DCQ RFG	TDFN 2x2	3,000pcs / 7" Reel

Note:

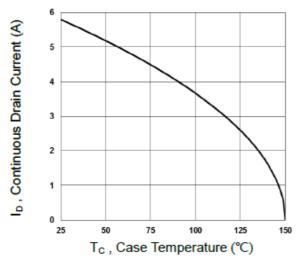
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition



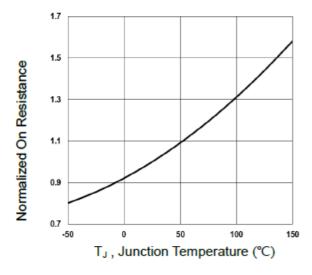
CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

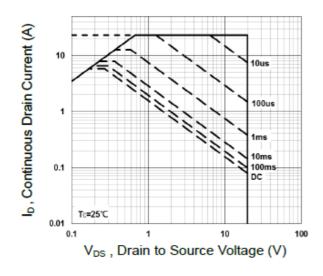
Continuous Drain Current vs. T_C



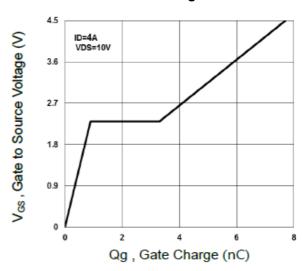
On-Resistance vs. Junction Temperature



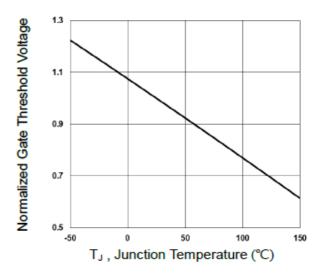
Maximum Safe Operating Area



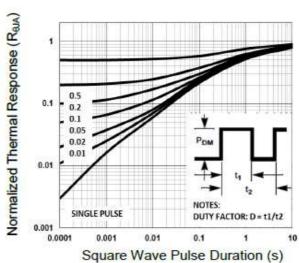
Gate Charge



Threshold Voltage vs. Junction Temperature



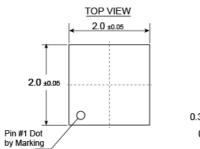
Normalized Thermal Transient Impedance Curve

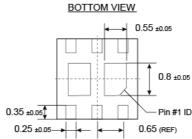


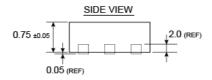


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

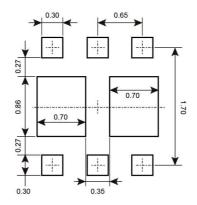
TDFN2x2



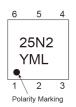




SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar

S =May T =Jun U =Jul V =Aug W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code (1~9, A~Z)



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